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ESSCIRC 2019 Table of Contents

A1L-A Joint Plenary 1: Edoardo Charbon, EPFL
Date: Tuesday, September 24, 2019
Time: 09:00 - 09:40
Room: Main Auditorium A & B

Cryo-CMOS Electronics for Quantum Computing Applications 1
Edoardo Charbon
Delft University of Technology, Netherlands

A2L-A Joint Plenary 2: Franck Arnaud, STMicroelectronics
Date: Tuesday, September 24, 2019
Time: 09:40 - 10:20
Room: Main Auditorium A & B

28nm FDSOI Platform with Embedded PCM for IoT, ULP, Digital, Analog, Automotive and Others Applications 7
Franck Arnaud, Sebastien Haendler, Sylvain Clerc, Rossella Ranica, Anna Gandolfo, Olivier Weber
STMicroelectronics, Italy; STMicroelectronics, France

B1L-A Joint Plenary 3: Toshio Yanagida, Osaka University
Date: Wednesday, September 25, 2019
Time: 09:00 - 09:40
Room: Main Auditorium A & B

Single Molecule Nano-Science: Noise and Function of Life ..... N/A
Toshio Yanagida
Osaka University, Japan

C1L-A Joint Plenary 4: Donhee Ham, Harvard University
Date: Thursday, September 26, 2019
Time: 09:00 - 09:40
Room: Main Auditorium A & B

CMOS Interface with Biological Molecules and Cells 13
Jeffrey Abbott, Tianyang Ye, Hongkun Park, Donhee Ham
Harvard University, United States

A5L-A ESSCIRC Keynote 1: Ram K. Krishnamurthy, Intel

Date: Tuesday, September 24, 2019
Time: 15:50 - 16:30
Room: Main Auditorium A

Machine Learning and Hardware Security Technologies for the IoT Era: Challenges and Opportunities ..... N/A
Ram K. Krishnamurthy
Intel Corporation, United States

B3L-A ESSCIRC Keynote 2: Jeff Walling, Tyndall National Institute

Date: Wednesday, September 25, 2019
Time: 13:30 - 14:10
Room: Main Auditorium A

The Switched-Capacitor Power Amplifier: a Key Enabler for Future Communications Systems 18
Jeffrey Walling
Tyndall National Institute, Ireland

C3L-A ESSCIRC Keynote 3: Pieter Harpe, TU Eindhoven

Date: Thursday, September 26, 2019
Time: 13:30 - 14:10
Room: Main Auditorium A

Low-Power SAR ADCs: Trends, Examples and Future 25
Pieter Harpe, Hanyue Li, Yuting Shen
Eindhoven University of Technology, Netherlands

A3L-A Analog Techniques

Date: Tuesday, September 24, 2019
Time: 11:00 - 12:20
Room: Main Auditorium A
Chair(s): Jens Anders; *University of Stuttgart*
Piotr Kmon; *AGH UST*

A 0.98nW/kHz 33kHz Fully-Integrated Subthreshold-Region Operation RC Oscillator with Forward-Body-Biasing 29
Philex Fan, Anand Savanth, Benoît Labbe, Pranay Prabhat, James Myers
Arm Ltd, United Kingdom

A 13.5 Gb/s 5 mV-Sensitivity 26.8 ps-CLK-OUT Delay Triple-Latch Feed-Forward Dynamic Comparator in 28 nm CMOS 33
Athanasios Ramkaj, Michiel Steyaert, Filip Tavernier
Katholieke Universiteit Leuven, Belgium

Voltage References for the Ultra-Wide Temperature Range from 4.2K to 300K in 40-nm CMOS 37
Job van Staveren, Carmina García Almudever, Giordano Scappucci, Menno Veldhorst, Masoud Babaie, Edoardo Charbon, Fabio Sebastiano
Delft University of Technology, Netherlands

A3L-B High Performance Oscillators

Date: Tuesday, September 24, 2019
Time: 11:00 - 12:20
Room: Main Auditorium B
Chair(s): Kenichi Okada; *Tokyo Tech*
Ping Lu; *Silicon Labs*

A 184.6-dBc/Hz FOM 100-Khz Flicker Phase Noise Corner 30-GHz Rotary Travelling-Wave Oscillator Using Distributed Stubs in 22-nm FD-SOI 41
Mohamed Atef Shehata[2], Mike Keaveney[1], Robert Bogdan Staszewski[2]
[1]Analog Devices, Ireland; [2]University College Dublin, Ireland

A 19.5 GHz 28 nm CMOS Class-C VCO with Reduced 1/F Noise Upconversion 45
Alessandro Franceschin[3], Pietro Andreani[2], Fabio Padovan[1], Matteo Bassi[1], Roberto Nonis[1], Andrea Bevilacqua[3]
[1]Infineon Technologies AG, Austria; [2]Lund University, Sweden; [3]Università degli Studi di Padova, Italy

A 32 MHz Crystal Oscillator with Fast Start-Up Using Dithered Injection and Negative Resistance Boost 49
Markus Scholl, Tobias Saalfeld, Christoph Beyerstedt, Fabian Speicher, Jonas Meier, Michael Hanhart, Leo Rolff, Vahid Bonehi, Moritz Schrey, Ralf Wunderlich, Stefan Heinen
RWTH Aachen University, Germany

A 77/79-GHz Frequency Generator in 16-nm CMOS for FMCW Radar Applications Based on a 26-GHz Oscillator with Co-Generated Third Harmonic 53
Feng-Wei Kuo[2], Zhirui Zong[1], Huan-Neng Ron Chen[2], Lan-Chou Cho[2], Chewn-Pu Jou[2], Mark Chen[2], Robert Bogdan Staszewski[3]
[1]Delft University of Technology, Netherlands; [2]Taiwan Semiconductor Manufacturing Company, Taiwan; [3]University College Dublin, Ireland

A3L-C Hardware Security Circuits

Date: Tuesday, September 24, 2019
Time: 11:00 - 12:20
Room: Small Aula
Chair(s): Alex Fish; *Bar-Ilan University*
Makoto Ikeda; *University of Tokyo*

A 20F² Area-Efficient Differential NAND-Structured Physically Unclonable Function for Low-Cost IoT Security 57
Jongmin Lee, Minsun Kim, Gicheol Shin, Yoonmyung Lee
Sungkyunkwan University, Korea

PUF-Based Key Generation with Design Margin Reduction via In-Situ and PVT Sensor Fusion 61
Sachin Taneja, Massimo Alioto
National University of Singapore, Singapore

An Inherently Secure FPGA Using PUF Hardware-Entanglement and Side-Channel Resistant Logic in 65nm Bulk CMOS 65
Burak Erbagci, Nail Etkin Can Akkaya, Cagri Erbagci, Ken Mai
Carnegie Mellon University, United States

Power Analysis Resilient SRAM Design Implemented with a 1% Area Overhead Impedance Randomization Unit for Security Applications 69
Robert Giterman[3], Maoz Wicentowski[1], Oron Chertkow[2], Ilan Sever[2], Ishai Kehati[1], Yoav Weizman[1], Osnat Keren[1], Alexander Fish[1]
[1]Bar Ilan University, Israel; [2]Dolphin Integration, Israel; [3]École Polytechnique Fédérale de Lausanne, Switzerland

A3L-D Biomedical Interfaces

Date: Tuesday, September 24, 2019
Time: 11:00 - 12:20
Room: Conference Room
Chair(s): Michael Mark; *Infineon*
Roman Genov; *University of Toronto*

A 20 Channel EMG SoC with an Integrated 32b RISC Core for Real-Time Wireless Prosthetic Control 73
Marc Pons Sole, Komail Badami, Jian Deng, Themistoklis Mavrogordatos, Erfan Azarkhish, Loic Zahnd, Costantino Cosentino, Marcin Augustyniak, Yingyun Zha, Andre Bischof, Lorenzo Bergamini, Philippe Dallemagne, Stephane Emery
CSEM SA, Switzerland

A Bidirectional Brain Computer Interface with 64-Channel Recording, Resonant Stimulation and Artifact Suppression in Standard 65nm CMOS 77
John Uehlin[2], William Anthony Smith[1], Venkata Rajesh Pamula[2], Steve Perlmutter[2], Visvesh Sathe[2], Jacques Christophe Rudell[2]
[1]SpaceX, United States; [2]University of Washington, United States

A 5-Channel Unipolar Fetal-ECG Readout IC for Patch Based Fetal Monitoring 81
Roland van Wegberg[3], Wim Sijbers[2], Shuang Song[2], Arjan Breeschoten[3], Peter Vis[3], Mario Konijnenburg[3], Hui Jiang[3], Michiel Rooijakkers[1], Torfinn Berset[1], Julien Penders[1], Chris van Hoof[2], Nick van Helleputte[2]
[1]Bloom Technologies, Belgium; [2]imec, Belgium; [3]imec/Holst Centre, Netherlands

A4L-A Imaging and Radiation

Date: Tuesday, September 24, 2019
Time: 14:00 - 15:20
Room: Main Auditorium A
Chair(s): Angel Rodriguez-Vazquez; *CSIC*
Antoine Dupret; *CEA*

SPC Pixel IC with 9.4 e− rms Offset Spread, 60 e− rms Enc and 70 kfps Frame Rate 85
Rafal Kleczek[1], Piotr Kmon[1], Piotr Maj[1], Robert Szczygiel[1], Pawel Grybos[1], Yasukazu Nakaye[2], Takuto Sakumura[2], Taguchi Takeyoshi[2]
[1]AGH University of Science and Technology, Poland; [2]Rigaku Corporation, Japan

A 16 × 8 Digital-SiPM Array with Distributed Trigger Generator for Low SNR Particle Tracking 89
Enrico Manuzzato[1], Leonardo Gasparini[1], Matteo Perenzoni[1], Yu Zou[1], Luca Parmesan[1], Giuseppe Battistoni[3], Micol De Simoni[2], Yunsheng Dong[3], Marta Fischetti[2], Eliana Gioscio[4], Ilaria Mattei[3], Riccardo Mirabelli[4], Vincenzo Patera[4], Alessio Sarti[4], Angelo Schiavi[4], Adalberto Sciubba[4], Serena Valle[3], Giacomo Traini[4], Michela Marafini[4]
[1]Fondazione Bruno Kessler, Italy; [2]INFN Sezione di Roma, Italy; [3]INFN Sezione Milano, Italy; [4]Museo Storico della Fisica e Centro Studi e Ricerche E. Fermi, Italy

A 128 × 128 SPAD Dynamic Vision-Triggered Time of Flight Imager 93
Francesco Mattioli Della Rocca[2], Hanning Mai[2], Sam Hutchings[2], Tarek Al Abbas[2], Andreas Tsiamis[2], Peter Lomax[2], Istvan Gyongy[2], Neale Dutton[1], Robert Henderson[2]
[1]STMicroelectronics, United Kingdom; [2]University of Edinburgh, United Kingdom

A Low-Power VGA Vision Sensor with Event Detection Through Motion Computation Based on Pixel-Wise Double-Threshold Background Subtraction and Local Binary Pattern Coding 97
Yu Zou, Massimo Gottardi, Michela Lecca, Matteo Perenzoni
Fondazione Bruno Kessler, Italy

A4L-B PLLs

Date: Tuesday, September 24, 2019
Time: 14:00 - 15:20
Room: Main Auditorium B
Chair(s): Martin Flatscher; *Infineon*
Jaehyouk Choi; *Ulsan National University of Science and Technology (UNIST)*

A 78 fs RMS Jitter Injection-Locked Clock Multiplier Using Transformer-Based Ultra-Low-Power VCO 101
Zheng Sun, Hanli Liu, Dingxin Xu, Hongye Huang, Bangan Liu, Zheng Li, Jian Pang, Teruki Someya, Atsushi Shirane, Kenichi Okada
Tokyo Institute of Technology, Japan

A Self-Calibrated Fractional-N PLL for WiFi 6 / 802.11ax in 28nm FDSOI CMOS 105
Gerasimos Vlachogiannakis, Charis Basetas, Georgia Tsirimokou, Chrysoula Vassou, Konstantinos Vastarouchas, Aidonia Georgiadou, Ioulia Sotiriou, Timothea Korfiati, Savvas Sgourenas
Adveos Microelectronic Systems, Greece

A 22.5-27.7GHz Fast-Lock Bang-Bang Digital PLL in 28nm CMOS for Millimeter-Wave Communication with 220fs RMS Jitter 109
Cheng-Hsueh Tsai[2], Federico Pepe[3], Giovanni Mangraviti[1], Zhiwei Zong[2], Jan Craninckx[1], Piet Wambacq[2]
[1]imec, Belgium; [2]imec and Vrije Universiteit Brussel, Belgium; [3]Università degli Studi di Pavia, Italy

A4L-C Digital Interface and Compensation Circuits

Date: Tuesday, September 24, 2019
Time: 14:00 - 15:20
Room: Small Aula
Chair(s): Stefan Rusu; *TSMC North America*
Atila Alvandpour; *Linkoping University*

Min-Delay Margin/Error Detection and Correction for Flip-Flops and Pulsed Latches in 10nm CMOS 113
Pascal Meinerzhagen, Sandip Kundu, Andres Malavasi, Trang Nguyen, Muhammad Khellah, James Tschanz, Vivek De
Intel Corporation, United States

An All-Digital, VMAX-Compliant, and Stable Distributed Charge Injection Scheme for Fast Mitigation of Voltage Droop 117
Suyoung Bang, Minki Cho, Pascal Meinerzhagen, Andres Malavasi, Muhammad Khellah, James Tschanz, Vivek De
Intel Corporation, United States

A 10.8pJ/Bit Pulse-Position Inductive Transceiver for Low-Energy Wireless 3D Integration 121
Benjamin Fletcher[2], Shidhartha Das[1], Terrence Mak[2]
[1]Arm Ltd, United Kingdom; [2]University of Southampton, United Kingdom

A Mixed-Signal Control Core for a Fully Integrated Semiconductor Quantum Computer System-on-Chip 125
Imran Bashir[1], Mike Asker[1], Cagri Cetintepe[2], Dirk Leipold[1], Ali Esmailiyan[2], Hongying Wang[2], Teerachot Siriburanon[2], Panagiotis Giounanlis[2], Elena Blokhina[2], Krzysztof Pomorski[2], Robert Bogdan Staszewski[2]
[1]Equal1 Labs, United States; [2]University College Dublin, United States; [2]University College Dublin, Ireland; [2]University College Dublin, Turkey

A4L-D Energy Harvesting

Date: Tuesday, September 24, 2019
Time: 14:00 - 15:20
Room: Conference Room
Chair(s): Drago Strle; *University of Lubljana*
Michiel Steyaert; *KU Leuven*

An Energy Harvester Using Image Sensor Pixels with Cold Start and Over 96% MPPT Efficiency 129
Nishit Shah[2], Pedram Lajevardi[1], Ken Wojciechowski[1], Christoph Lang[1], Boris Murmann[2]
[1]Robert Bosch Research and Technology Center, United States; [2]Stanford University, United States

A 95.3% Peak Efficiency 38mV Overshoot and 5mV/A Load Regulation Hysteretic Boost Converter with Anti-Phase Emulate Current Control 133
Wanyuan Qu[2], Donglie Gu[2], Haixiao Cao[2], Xu Yang[2], Jianxiong Xi[2], Lenian He[2], Shuo Dong[1]
[1]Shanghai Aerospace Electronic Technology Institute, China; [2]Zhejiang University, China

A Dual-Frequency Dual-Input-Dual-Output Interface for Thermoelectric Energy Harvesting and Recycling with 82.9% Efficiency 137
Qin Kuai, Qiping Wan, Philip K. T. Mok
Hong Kong University of Science and Technology, Hong Kong

Area Constrained Multi-Source Power Management for Thermoelectric Energy Harvesting 141
Jacob Goeppert[1], Simon Braun[1], David Pellhammer[1], Mohammad Amayreh[1], Joachim Leicht[2], Matthias Keller[1], Yiannos Manoli[1]
[1]Albert-Ludwigs-Universität Freiburg, Israel; [1]Albert-Ludwigs-Universität Freiburg, Germany; [2]Hahn Schickard, Germany

A6L-A Analog Systems

Date: Tuesday, September 24, 2019
Time: 16:40 - 18:00
Room: Main Auditorium A
Chair(s): Jelle Van Rethy; *Melexis*
Hugo Veenstra; *Philips*

A -81.6dBm Sensitivity Ultrasound Transceiver in 65nm CMOS for Symmetrical Data-Links 145
Gönenç Berkol, Peter Baltus, Pieter Harpe, Eugenio Cantatore
Eindhoven University of Technology, Netherlands

Optical Receiver with Schottky Photodiode and TIA with High Gain Amplifier in 28nm Bulk CMOS 149
Wouter Diels, Michiel Steyaert, Filip Tavernier
Katholieke Universiteit Leuven, Belgium

A Class-D Amplifier with Digital PWM and Digital Loop-Filter Using a Mixed-Signal Feedback Loop 153
Mario Auer, Timucin Karaca
Graz University of Technology, Austria

A 30V 2A Real-Time Programmable Solid-State Circuit Breaker with Improved Detection-Speed and Enhanced Power-Efficiency 157
Yong Qu, Wei Shu, Yang Kang, Joseph S. Chang
Nanyang Technological University, Singapore

A6L-B Temperature Sensors

Date: Tuesday, September 24, 2019
Time: 16:40 - 18:00
Room: Main Auditorium B
Chair(s): Michiel Pertijs; *TU Delft*
Martijn Snoeij; *Texas Instruments*

A 0.34-571nW All-Dynamic Versatile Sensor Interface for Temperature, Capacitance, and Resistance Sensing 161
Haoming Xin[1], Martin Andraud[2], Peter Baltus[1], Eugenio Cantatore[1], Pieter Harpe[1]
[1]Eindhoven University of Technology, Netherlands; [2]Katholieke Universiteit Leuven, Belgium

A 5800 µm² Resistor-Based Temperature Sensor with a One-Point Trimmed 3σ Inaccuracy of ±1.1 °C from -50 to 105 °C in 65 nm CMOS 165
Yongtae Lee[2], Woojun Choi[2], Taewoong Kim[2], Seungwoo Song[2], Kofi Makinwa[1], Youngcheol Chae[2]
[1]Delft University of Technology, Netherlands; [2]Yonsei University, Korea

A No-Trim, Scaling-Friendly Thermal Sensor in 16nm FinFET Using Bulk-Diodes As Sensing Elements 169
Matthias Eberlein, Harald Pretl
Intel Corporation, Germany; Intel Corporation, Austria

A6L-C TX Techniques

Date: Tuesday, September 24, 2019
Time: 16:40 - 18:00
Room: Small Aula
Chair(s): Francois Rivet; *IMS Bordeaux*
Lars Sundstrom; *Ericsson*

70-90GHz Self-Tuned Polyphase Filter for Wideband I/Q LO Generation in a 55nm BiCMOS Transmitter 173
Farshad Piri[1], Elham Rahimi[3], Matteo Bassi[1], Francesco Svelto[2], Andrea Mazzanti[2]
[1]Infineon Technologies AG, Austria; [2]Università degli Studi di Pavia, Italy; [3]Università di Pavia, Italy

Broadband Fully Integrated GaN Power Amplifier with Embedded Minimum Inductor Bandpass Filter and AM-PM Compensation..... 177
Gholamreza Nikandish, Robert Bogdan Staszewski, Anding Zhu
University College Dublin, Ireland

An 11 GHz–Bandwidth Variable Gain Ka–Band Power Amplifier for 5G Applications..... 181
Reza Bagger, Henrik Sjöland
Lund University, Sweden

B2L-A High Resolution SAR ADC

Date: Wednesday, September 25, 2019
Time: 10:20 - 12:00
Room: Main Auditorium A
Chair(s): Piero Malcovati; *University of Pavia*
Qiang Li; *University of Electronic Science and Technology of China (UESTC)*

A Capacitor Dielectric Relaxation Effect Cancellation Circuit in a 12-bit, 1 MSps, 5.0 V SAR ADC on a 28 nm Embedded Flash Memory Microcontroller 185
Tetsuo Matsui, Keisaku Sento, Tomohiko Ebata, Atsuhiko Ishibashi
Renesas Electronics Corporation, Japan

Machine Learning Based Prior-Knowledge-Free Calibration for Split Pipelined-SAR ADCs with Open-Loop Amplifiers Achieving 93.7-dB SFDR 189
Tianli Zhang, Yuefeng Cao, Shumin Zhang, Chixiao Chen, Fan Ye, Junyan Ren
Fudan University, China

A 500 MS/s 10-Bit Single-Channel SAR ADC with a Double-Rate Comparator 193
Qingjun Fan[3], Runxi Zhang[2], Phaneendra Bikkina[1], Esko Mikkola[1], Jinghong Chen[3]
[1]Alphacore Inc., United States; [2]East China Normal University, China; [3]University of Houston, United States

A 625MS/s, 12-Bit, SAR Assisted Pipeline ADC with Effective Gain Analysis for Inter-Stage Ringamps 197
Yongzhen Chen, Xingchen Shen, Zhekan Ni, Jingchao Lan, Chixiao Chen, Fan Ye, Junyan Ren
Fudan University, China

B2L-B Wireless RX

Date: Wednesday, September 25, 2019
Time: 10:20 - 12:00
Room: Main Auditorium B
Chair(s): Stefan Andersson; *Ericsson*
Dominique Morche; *CEA*

A 260 MHz RF Bandwidth Mixer-First Receiver with 3rd Order Current-Mode Filtering TIA 201
Giacomo Pini[1], Danilo Manstretta[2], Rinaldo Castello[2]
[1]Catena Microelectronics B.V., Italy; [2]Università degli Studi di Pavia, Italy

An 8.5pJ/Bit Ultra-Low Power Wake-Up Receiver Using Schottky Diodes for IoT Applications 205
Mahmoud Elhebeary, Li-Yang Chen, Sudhakar Pamarti, Chih-Kong Ken Yang
University of California, Los Angeles, United States

A 915 MHz, 499 µW, −99 dBm, and 100 kbps BFSK Direct Conversion Receiver 209
Keun-Mok Kim[2], Eui-Rim Jeong[1], Kyung-Sik Choi[2], Subin Kim[2], Byeonghun Yun[2], Hyunki Jung[2], Wonkab Oh[3], Jinho Ko[3], Sang-Gug Lee[2]
[1]Hanbat University, Korea; [2]KAIST, Korea; [3]PHYCHIPS Inc., Korea

A Wideband IF Receiver Module for Flexibly Scalable mmWave Beamforming Combining and Interference Cancellation 213
Rehman Akbar[2], Eric A. M Klumperink[3], Nuutti Tervo[2], Muhammad Yasir Javed[2], Kari Stadius[1], Timo Rahkonen[2], Aarno Pärssinen[2]
[1]Aalto University, Finland; [2]University of Oulu, Finland; [3]University of Twente, Netherlands

A 19-GHz Pulsed-Coherent ToF Receiver with 40-µm Precision for Laser Ranging Systems 217
Li-Yang Chen, Chih-Kong Ken Yang
University of California, Los Angeles, United States

B2L-C MM-Wave Frequency Multipliers

Date: Wednesday, September 25, 2019
Time: 10:20 - 12:00
Room: Small Aula
Chair(s): Salvatore Levantino; *Politecnico di Milano*
Dietmar Kissinger; *Ulm University*

A 39GHz Frequency Tripler with >40 dBc Harmonic Rejection for 5G Communication Systems in 28 nm Bulk CMOS 221
Matteo Bassi[1], Giovanni Boi[1], Fabio Padovan[1], Jonas Fritzin[1], Stefano Di Martino[1], Daniel Knauder[1], Andrea Bevilacqua[2]
[1]Infineon Technologies AG, Austria; [1]Infineon Technologies AG, Germany; [2]Università degli Studi di Padova, Italy

A 57-74GHz Tail-Switching Injection-Locked Frequency Tripler in 28nm CMOS..... 225
Lorenzo Iotti, Greg Lacaille, Ali Niknejad
University of California, Berkeley, United States

40GHz Frequency Tripler with High Fundamental and Harmonics Rejection in 55nm SiGe-BiCMOS 229
Mahmoud Mahdipour Pirbazari, Federico Pepe, Andrea Mazzanti
Università degli Studi di Pavia, Italy

B2L-D Machine Learning and Accelerators

Date: Wednesday, September 25, 2019
Time: 10:20 - 12:00
Room: Conference Room
Chair(s): Andreas Burg; *EPFL*
Viktor Owall; *Lunds University*

A 8.93 TOPS/W LSTM Recurrent Neural Network Accelerator Featuring Hierarchical Coarse-Grain Sparsity with All Parameters Stored on-Chip 233
Deepak Kadetotad, Visar Berisha, Chaitali Chakrabarti, Jae-Sun Seo
Arizona State University, United States

A 213.7-µW Gesture Sensing System-on-Chip with Self-Adaptive Motion Detection and Noise-Tolerant Outermost-Edge-Based Feature Extraction in 65-nm 237
Van Loi Le[2], Taegeun Yoo[2], Ju Eon Kim[1], Kwang-Hyun Baek[1], Tony Tae-Hyoung Kim[2]
[1]Chung-Ang University, Korea; [2]Nanyang Technological University, Singapore

Physically Tightly Coupled, Logically Loosely Coupled, Near-Memory BNN Accelerator (PTLL-BNN) 241
Yun-Chen Lo, Yu-Chun Kuo, Yun-Sheng Chang, Jian-Hao Huang, Jun-Shen Wu, Wen-Chien Ting, Tai-Hsing Wen, Ren-Shuo Liu
National Tsing Hua University, Taiwan

A 354 Mb/s 0.37mm² 151mW 32-User 256-QAM Near-MAP Soft-Input Soft-Output Massive MU-MIMO Data Detector in 28nm CMOS 245
Charles Jeon[2], Oscar Castañeda[1], Christoph Studer[1]
[1]Cornell University, United States; [2]Intel Labs & Cornell University, United States

B4L-A Amplifiers and Filters

Date: Wednesday, September 25, 2019
Time: 14:20 - 15:40
Room: Main Auditorium A
Chair(s): Viola Schaffer; *Texas Instruments*
Bruno Vaz; *Xilinx*

A 0.06-3.4 MHz 92 µW Analog FIR Channel Selection Filter with Very Sharp Transition Band for IoT Receivers 249
Bart Thijssen[2], Eric A. M Klumperink[2], Philip Quinlan[1], Bram Nauta[2]
[1]Analog Devices, Ireland; [2]University of Twente, Netherlands

A 28nm Bulk-CMOS 50MHz 18 dBm-IIP3 Active-RC Analog Filter Based on 7 GHz UGB OTA 253
Federico Fary, Luca Mangiagalli, Elia Arturo Vallicelli, Marcello De Matteis, Andrea Baschirotto
Università degli Studi di Milano-Bicocca, Italy

An Auto-Zero Stabilized Voltage Buffer with a Trimmed Input Current of 0.2pA..... 257
Thije Rooijers, Johan Huijsing, Kofi Makinwa
Delft University of Technology, Netherlands

A 185 µW −105.1 dB THD 88.6 dB SNDR Negative-R Stabilized Audio Preamplifier 261
Seungwoo Song, Changuk Lee, Moonhyung Jang, Youngcheol Chae
Yonsei University, Korea

B4L-B Wireline

Date: Wednesday, September 25, 2019
Time: 14:20 - 15:40
Room: Main Auditorium B
Chair(s): Gerrit den Besten; *NXP*
Declan Carey; *Xilinx*

A 112 Gb/s PAM-4 Transmitter with a 2-Tap Fractional-Spaced FFE in 65 nm CMOS 265
Hao Ding[2], Xuqiang Zheng[2], Danyu Wu[2], Lei Zhou[2], Jin Wu[2], Fangxu Lv[1], Jianye Wang[1], Xinyu Liu[2]
[1]Air Force Engineering University, China; [2]Institute of Microelectronics of Chinese Academy of Sciences, China

A PAM-8 Wireline Transceiver with Receiver Side PWM (Time-Domain) Feed Forward Equalization Operating from 12-to-39.6Gb/s in 65nm CMOS 269
Yusang Chun, Ashwin Ramachandran, Tejasvi Anand
Oregon State University, United States

A 2-Tap Switched Capacitor FFE Transmitter Achieving 1-20 Gb/s at 0.72-0.62 pJ/Bit 273
Nicholas Sutardja, Jaeduk Han, Nathan Narevsky, Elad Alon
University of California, Berkeley, United States

A 26Gbps 3D-Integrated Silicon Photonic Receiver in BiCMOS-55nm and PIC25G with -15.2Dbm OMA Sensitivity 277
Farhad Bozorgi[3], Melchiorre Bruccoleri[2], Matteo Repossi[2], Enrico Temporiti[1], Andrea Mazzanti[3], Francesco Svelto[3]
[1]eSilicon, Italy; [2]STMicroelectronics, Italy; [3]Università degli Studi di Pavia, Italy

B4L-C Power Management

Date: Wednesday, September 25, 2019
Time: 14:20 - 15:40
Room: Small Aula
Chair(s): Christoph Sandner; *Infineon*
Ravi Karadi; *NXP*

A Temperature Compensated 61W Class-E Soft-Switching GaN-Based Active Diode Rectifier for Wireless Power Transfer Applications 281
Bo-Kuan Wu[1], Shang-Hsien Yang[1], Ke-Horng Chen[1], Ying-Hsi Lin[2], Shian-Ru Lin[2], Tsung-Yen Tsai[2]
[1]National Chiao Tung University, Taiwan; [2]Realtek Semiconductors, Taiwan

Adaptive Peak Average Current Control LED Driver for Automotive Lighting 285
Pavel Horsky, Jan Plojhar, Jiri Daniel
ON Semiconductor, Czech Rep.

A Single-Controller-Four-Output Analog-Assisted Digital LDO with Adaptive-Time-Multiplexing Control in 65-nm CMOS 289
Yasu Lu, Feng Chen, Philip K. T. Mok
Hong Kong University of Science and Technology, Hong Kong

A 130 nm CMOS Dual Input-Polarity DC-DC Converter for Low Power Applications 293
Alberto Gatti[2], Giorgio Spiazzi[1], Andrea Gerosa[1], Andrea Neviani[1], Andrea Bevilacqua[1]
[1]Università degli Studi di Padova, Italy; [2]Università di Padova, Italy

C2L-A High-Speed ADC

Date: Thursday, September 26, 2019
Time: 10:20 - 12:00
Room: Main Auditorium A
Chair(s): Georges Gielen; *KU Leuven*
Klaas Bult; *Analog Design Consult B.V.*

A 1 GS/s 8-Bit Two-Step SAR ADC with Fast Noise Reduction and Background Calibration 297
Qingjun Fan, Jinghong Chen
University of Houston, United States

A 2.4 GS/s 10-Bit Time-Interleaved SAR ADC with a Bypass Window and Opportunistic Offset Calibration 301
Qingjun Fan, Jinghong Chen
University of Houston, United States

An 8-Bit 2.8 GS/s Flash ADC with Time-Based Offset Calibration and Interpolation in 65 nm CMOS 305
Xi Yang[1], Seung-Jun Bae[2], Hae-Seung Lee[1]
[1]Massachusetts Institute of Technology, United States; [2]Samsung Electronics, Korea

An 8-Bit 10-GHz 21-mW Time-Interleaved SAR ADC with Grouped DAC Capacitors and Dual-Path Bootstrapped Switch 309
Eric Swindlehurst[1], Hunter Jensen[1], Alexander Petrie[1], Yixin Song[1], Yen-Cheng Kuan[2], Mau-Chung Frank Chang[3], Jieh-Tsorng Wu[2], Shiuh-Hua Wood Chiang[1]
[1]Brigham Young University, United States; [2]National Chiao Tung University, Taiwan; [3]University of California, Los Angeles, United States

C2L-B Sensor Interfaces

Date: Thursday, September 26, 2019
Time: 10:20 - 12:00
Room: Main Auditorium B
Chair(s): Paul Walsh; *Cypress Semi*
Robert Henderson; *University of Edinburgh*

An Always-on 0.53-to-13.4 mW Power-Scalable Touchscreen Controller for Ultrathin Touchscreen Displays with Current-Mode Filter and Incremental Hybrid ΔΣ ADC 313
Young-Ha Hwang, Jonghyun Oh, Jiheon Park, Yoonho Song, Jung-Hun Park, Jun-Eun Park, Deog-Kyoon Jeong
Seoul National University, Korea

A 64-Channel, 1.1-pA-Accurate On-Chip Potentiostat for Parallel Electrochemical Monitoring 317
Peishuo Li[2], Tom Molderez[2], Frederik Ceyssens[2], Korneel Rabaey[1], Marian Verhelst[2]
[1]Ghent University, Belgium; [2]Katholieke Universiteit Leuven, Belgium

An Integrated Readout for Current Sensing Based on a ΣΔ Modulator with Switched Capacitor Feedback..... 321
Mahdi Rajabzadeh[2], Matthias Häberle[2], Ankesh Jain[1], Maurits Ortmanns[2]
[1]Indian Institute of Technology Delhi, India; [2]Universität Ulm, Germany

An Integrated Programmable High-Voltage Bipolar Pulser with Embedded Transmit/Receive Switch for Miniature Ultrasound Probes 325
Mingliang Tan[1], Eunchul Kang[1], Jae-Sung An[1], Zu-Yao Chang[1], Philippe Vince[2], Nicolas Sénégond[2], Michiel Pertijs[1]
[1]Delft University of Technology, Netherlands; [2]Vermon S.A., France

C2L-C Millimeter-wave Power Amplifiers

Date: Thursday, September 26, 2019
Time: 10:20 - 12:00
Room: Small Aula
Chair(s): Domine Leenaerts; *NXP*
Marc Tiebout; *Infineon*

A 76-81 GHz CMOS PA with 16-dBm PSAT and 30-dB Amplitude Control for MIMO Automotive Radars 329
Dongfang Pan[3], Zongming Duan[3], Liguo Sun[3], Shita Guo[2], Lin Cheng[3], Ping Gui[1]
[1]Southern Methodist University, United States; [2]Texas Instruments, United States; [3]University of Science and Technology of China, China

An 18 dBm 155-180 GHz SiGe Power Amplifier Using a 4-Way T-Junction Combining Network 333
Maciej Kucharski[1], Herman Ng[1], Dietmar Kissinger[2]
[1]Leibniz-Institut für innovative Mikroelektronik, Germany; [2]Universität Ulm, Germany

A 112-142GHz Power Amplifier with Regenerative Reactive Feedback Achieving 17dBm Peak Psat at 13% PAE 337
Akshay Visweswaran[1], Bastien Vignon[1], Xinyan Tang[1], Steven Brebels[1], Bjorn Debaillie[1], Piet Wambacq[2]
[1]imec, Belgium; [2]imec and Vrije Universiteit Brussel, Belgium

C2L-D Memory-Centric Design

Date: Thursday, September 26, 2019
Time: 10:20 - 12:00
Room: Conference Room
Chair(s): Tobias Gemmeke; *RWTH Aachen*
Mark Anders; *Intel Corp.*

C3SRAM: In-Memory Computing SRAM Macro Based on Capacitive-Coupling Computing 341
Zhewei Jiang[2], Shihui Yin[1], Jae-Sun Seo[1], Mingoo Seok[2]
[1]Arizona State University, United States; [2]Columbia University, United States

A 1-16b Precision Reconfigurable Digital In-Memory Computing Macro Featuring Column-Mac Architecture and Bit-Serial Computation 345
Hyunjoon Kim, Qian Chen, Taegeun Yoo, Tony Tae-Hyoung Kim, Bongjin Kim
Nanyang Technological University, Singapore

2 Mb Embedded Phase Change Memory with 16 ns Read Access Time and 5 Mb/s Write Throughput in 90 nm BCD Technology for Automotive Applications 349
Marcella Carissimi[1], Riccardo Zurla[2], Chantal Auricchio[1], Emanuela Calvetti[1], Laura Capecchi[1], Luigi Croce[1], Stefano Zanchi[1], Vikas Rana[1], Preeti Mishra[1], Ritesh Mukherjee[1], Vivek Tyagi[1], Fabio Disegni[1], Davide Manfrè[1], Cesare Torti[1], Daniele Gallinari[1], Sandro Rossi[1], Andrea Gambero[1], Donatella Brambilla[1], Paola Zuliani[1], Alessandro Cabrini[2], Guido Torelli[2], Marco Pasotti[1]
[1]STMicroelectronics, Italy; [1]STMicroelectronics, India; [2]Università degli Studi di Pavia, Italy

C4L-A Sigma-Delta and Time-Based ADC

Date: Thursday, September 26, 2019
Time: 14:20 - 15:40
Room: Main Auditorium A
Chair(s): Ana Rusu; *KTH Royal Institute of Technology*
Lucien Breems; *NXP*

A 4GS/s 39.9dB SNDR 11.7mW Hybrid Voltage-Time Two-Step ADC with Feed-Forward Ring Oscillator Based TDCs 353
Yifan Lyu, Filip Tavernier
Katholieke Universiteit Leuven, Belgium

A Simultaneous Multi-Band Continuous-Time ΔΣ ADC with 90MHz Aggregate Bandwidth in 40nm CMOS 357
John Bell, Michael Flynn
University of Michigan, United States

A 94.3 dB SFDR, 91.5 dB DR, 200 kS/s CT Incremental Delta-Sigma Modulator with Differentially Reset FIR Feedback 361
Mohamed A. Mokhtar, Patrick Vogelmann, Michael Haas, Maurits Ortmanns
Universität Ulm, Germany

A 2-Channel ADC Using a Delta-Sigma Modulator Without Reset & a Modulated-Sinc-Sum Filter 365
Ramakrishnan Sivakum Ashwin Kumar, Nagendra Krishnapura
Indian Institute of Technology Madras, India

C4L-B Wireless TX

Date: Thursday, September 26, 2019
Time: 14:20 - 15:40
Room: Main Auditorium B
Chair(s): Andrea Mazzanti; *University of Pavia*
Jan Craninckx; *IMEC*

A Cellular Multiband DTC-Based Digital Polar Transmitter with -153 dBc/Hz Noise in 14nm FinFET 369
Yorgos Palaskas, Paolo Madoglio, Joern Angel, Jakob Tomasik, Sven Hampel, Petra Schubert, Peter Preyler, Thomas Mayer, Thomas Bauernfeind, Peter Plechinger, Ashoke Ravi, Ofir Degani, Rotem Banin, Eshel Gordon, Zdravko Boos
Intel Corporation, Austria; Intel Corporation, Germany; Intel Corporation, United States; Intel Corporation, Israel

Direct-Conversion I-Q Transmitter Front-End for 180 GHz with 80 GHz Bandwidth in 130 nm SiGe 373
Paul Stärke, Xin Xu, Corrado Carta, Frank Ellinger
Technische Universität Dresden, Germany

A Low Power Bluetooth Low-Energy Transmitter with a 10.5nJ Startup-Energy Crystal Oscillator 377
Omar Abdelatty[1], Henry Bishop[2], Yao Shi[1], Xing Chen[1], Abdullah Alghaihab[1], Benton Calhoun[2], David Wentzloff[1]
[1]University of Michigan, United States; [2]University of Virginia, United States

C4L-C RX and Imaging Techniques

Date: Thursday, September 26, 2019
Time: 14:20 - 15:40
Room: Small Aula
Chair(s): Patrick Reynaert; *KU Leuven*
Domenico Zito; *Aarhus University*

A Hybrid THz Imaging System with 3–3.5 THz 100-Pixel CMOS Imager and THz Quantum Cascade Laser Frequency Comb 381
Todd Joseph Smith[1], Anna Broome[2], Daniel Stanley[2], Jonas Westberg[1], Gerard Wysocki[1], Kaushik Sengupta[1]
[1]Princeton University, United States; [2]Stanford University, United States

A 28GHz Sliding-IF Receiver in 22nm FDSOI 385
Sher Fang[2], Frank Zhang[2], Abdellatif Bellaouar[2], Sherif Embabi[1]
[1]Globafoundries, United States; [2]Globalfoundries, United States

A Delay-Based LO Phase-Shifting Generator for a 2-5GHz Beamsteering Receiver in 28nm CMOS 389
Yury Antonov[1], Mahwish Zahra[1], Kari Stadius[1], Zahra Khonsari[2], Ilia Kempi[1], Toni Miilunpalo[1], Juha Inkinen[1], Vishnu Unnikrishnan[1], Lauri Anttila[3], Mikko Valkama[3], Marko Kosunen[1], Jussi Ryynänen[1]
[1]Aalto University, Finland; [2]GE Healthcare, Finland; [3]Tampere University, Finland